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Leaded Varistors

StandarD Series

Series/Type: SIOV-S10K50G3S5 Ordering code: B72210S0500K531

Date: 2005-09-22

Version: a

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StandarD Series SIOV-S10K50G3S5

SIOV nomenclature

S = Disk type

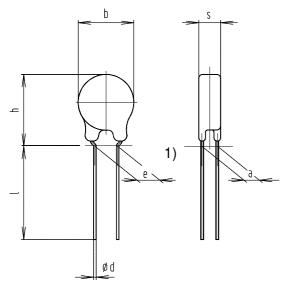
10 = Rated disk diameter

K = Tolerance of varistor voltage at 1mA: ± 10%

50 = Max. operating voltage V_{rms} G3 = Taping based on IEC 60286-2

S5 = Crimp style S5

Figure: Dimensions given in Millimeters (mm)



 $a = 1,4 \pm 1,0$ $I_{min} = n.a.$ $\varnothing d = 0,8 \pm 0,05$

1) seating plane in accordance with IEC

²⁾ measured above carrier tape

Electrical data:

Maximum Ratings (T=85°C)

Max. operating AC voltage		V_{RMS}	=	50 V
Max. operating DC voltage		V _{DC}	=	65 V
Surge current (8/20µs)	1 time	I _{max}	=	2500 A
Energy absorption (2ms)	1 time	W_{max}	=	8,4 J
Average power dissipation		P_{max}	=	0,40 W

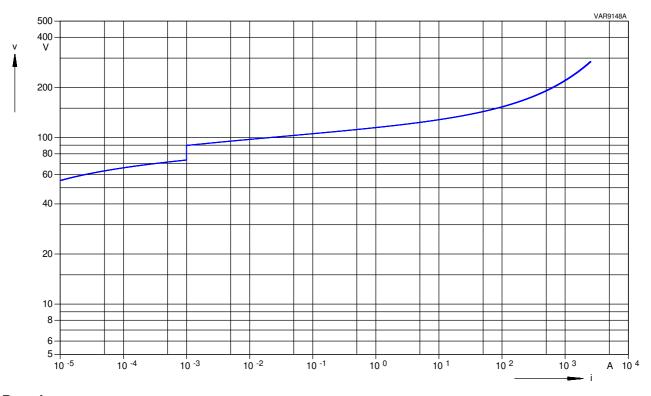
Characteristics (T=25°C)

Varistor voltage at 1mA	V_V	=	82 V ± 10%
Clamping voltage at 25 A (8/20µs)	$V_{C,max}$	=	135 V
Typ. capacitance at 1 kHz	C	=	950 pF

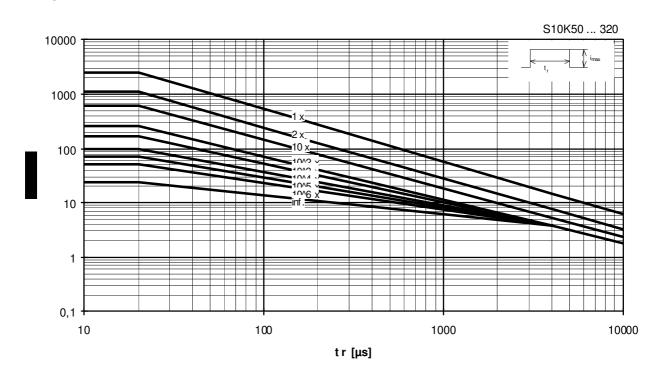


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V/I Characteristic:



Derating:

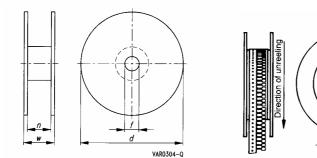


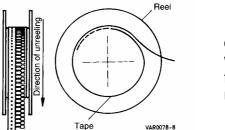


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Taping:

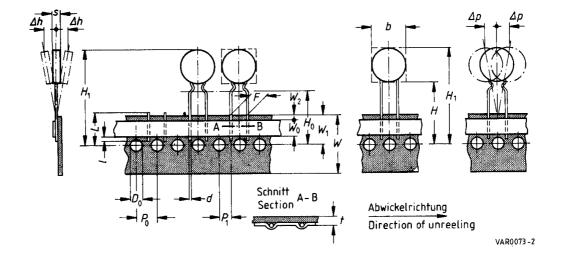
Package Unit: 750 pcs./reel





 $\begin{array}{lll} d_{max} & = & 360 \text{ mm} \\ w_{max} & = & 64 \text{ mm} \\ f & = & 31 \pm 1,0 \text{mm} \\ n & = & 55 \text{ mm (typ.)} \end{array}$

Lead spacing 7,5 mm





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Tape dimensions, in Millimeters (mm):

	1			
Definition	Symbol	Dimension	Tolerance	Remarks
Body diameter	b	12,0	max	
		,		
Body thickness	S	3,9	max	
Lead diameter	d	0,8	\pm 0,05	
Sprocket hole pitch	P _o	12,7	± 0,3	± 1mm/20 sprocket holes
Distance hole center to lead center	P ₁	8,95	± 0,8	
Lead spacing	F	7,5	± 0,8	measured above carrier tape
Component deviation	Δh			depends on s
Component deviation	Δр	0	± 2,0	measured at top of component body
Carrier tape width	W	18,0	± 0,5	
Adhesive tape width	Wo	11,0	min	Peel-off force ≥5N
Sprocket hole position	W ₁	9,0	+0,75/-0,5	
Adhesive tape position	W ₂	3,0	max	
Distance hole center to the top of the component	H ₁	45,0	max	
Seating plane height	H ₀	16,0	± 0,5	
Hole diameter	D ₀	4,0	± 0,2	
Total tape thickness	t	0,9	max	
Cutting level	L	11,0	max	



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Reliability Data:

	Characteristics	Test Methods/Description	Specifications
E	Varistor Voltage	The voltage between two terminals with the specified measuring current applied is called V_{ν} (1 mA _{DC} @ 0.2 - 2 s).	To meet the specified value.
L E	Clamping Voltage	The maximum voltage between two terminals with the specified standard impulse current (8/20µs) illustrated below applied.	To meet the specified value.
С		100 90 ——————————————————————————————————	
Т		10	
R		Ty Rea Time ye T. Decay time to half value ya O. Normal start I. Peak value	
I			
С	Surge current derating, 8/20 µs	100 surge currents (8/20 μs), unipolar, interval 30 s, amplitude corresponding to derating curve for 20 μs	∆ V/V (1 mA) ≤ 10 % (measured in direction of surge
Α	[F	current) No visible damage
L	Surge current derating, 2 ms	100 surge currents (2ms), unipolar, interval 120s, amplitude corresponding to derating curve for 2ms	Δ V/V (1 mA) ≤ 10 % (measured in direction of surge current) No visible damage



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	Characteristics	Test Methods/Description	Specifications
	Tensile strength	After gradually applying the force specified below and keeping the unit fixed for 10 seconds, the terminal shall be visually examined for any damage.	∆ V/V (1 mA) ≤ 5 % No break of solder joint, no wire break
М		Terminal diameter Force 0.5 mm 5 N 0.6 mm 10 N 0.8 mm 10 N 1.0 mm 20 N	
E	Vibration	After repeatedly applying a single harmonic vibration according to the table below. Thereafter, the unit shall be visually examined.	$ \Delta \text{ V/V (1 mA)} $ $\leq 5 \%$ No visible damage
С		frequency range: 10 55 Hz amplitude: 0.75 mm or 98 m/s² duration: 6 h (3 x 2 h) pulse: sine wave	
A	Solderability	After dipping the terminals to a depth of approximately 3 mm from the body in a soldering bath of 235°C for 5 seconds, the terminals shall be visually examined.	The inspection shall be carried out under adequate light with normal eyesight or
ı		terrimais shall be visually examined.	with the assistance of a magnifier capable of giving a magnification of 4
С			times to 10 times. The dipped surface shall be covered with a smooth and
A			bright solder coating with no more than small amounts of
L			scattered imperfections such as pinholes or unwetted or de-wetted areas. These imperfections shall not be concentrated in one area.



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	Characteristics	Test Methods/Description	Specifications
М	Resistance to	Each lead shall be dipped into a solder bath	\(\Delta \text{ V/V (1 mA) }
Е	soldering heat	having a temperature of 260 \pm 5°C to a point 2.0 to 2.5 mm from the body of the unit, be held	≤ 5 % No visible damage
С		there for 10 ± 1 s and then be stored at room	110 Violoto damago
Н		temperature and normal humidity for 1 to 2 hours. The change of V_v and mechanical	
Α		damages shall be examined.	
Ν	Electric strength	2500 V _{RMS} , 10 s	No breakdown
- 1		The varistor is placed in a container holding 1.6 \pm 0.2 mm diameter metal balls such that only the	
С		terminations of the varistor are protruding.	
Α		The specified voltage shall be applied between both terminals of the specimen connected	
L		together and the electrode inserted between the metal balls.	



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	Characteristics	Test Methods/Description	Specifications		
E N	Max. AC operating voltage	After being continuously applied the maximum allowable voltage at $85 \pm 2^{\circ}\text{C}$ for 1000 hours, the specimen shall be stored at room temperature and normal humidity for 1 to 2 hours. Thereafter, the change of V_v shall be measured.	Δ V/V (1 mA) ≤ 10 %		
V	Damp heat, steady state	The specimen shall be subjected to $40 \pm 2^{\circ}$ C, 90 to 95 % r.H. for 56 days without load and then stored at room temperature and normal humidity for 1 to 2 hours. Thereafter, the change of V_v	Δ V/V (1 mA) ≤ 10 %		
		shall be measured.			
R	Climatic sequence	The specimen shall be subjected to: a) dry heat at +85°C, 16 h b) damp heat, 1st cycle: 55°C, 93 % r.H., 24 h	∆ V/V (1 mA) ≤ 10 %		
0		c) cold, -40°C, 2 h d) damp heat, additional 5 cycles: 55°C, 93 % r.H., 24 h/cycle			
N		Then the specimen shall be stored at room temperature and normal humidity for 1 to 2 hours. Thereafter, the change of V _v shall be			
М		measured.			
E	Fast temperature cycling	The temperature cycle shown below shall be repeated 5 times. Then the specimen shall be stored at room temperature and normal humidity for 1 to 2 hours. The change of V _v and	$ \Delta \text{ V/V (1 mA)} $ $\leq 5 \%$ No visible damage		
N		mechanical damage shall be examined.			
т		$\begin{array}{cccc} \underline{Step} & \underline{Temperature~(^{\circ}C)} & \underline{Period~(min.)} \\ 1 & -40 \pm 3 & 30 \pm 3 \\ 2 & transition~time & < 10~s \\ 3 & 85 \pm 2 & 30 \pm 3 \end{array}$			
Α					
L					

 $\underline{\text{Note:}}\,$ More details can be found in the data book 'SIOV Metal Oxide Varistors', Ordering No. EPC: 62002-7600



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